

Isc N-Channel MOSFET Transistor

STW48NM60N

• FEATURES

- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



Switching applications

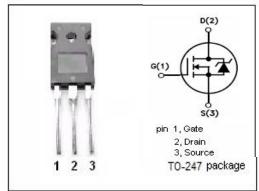


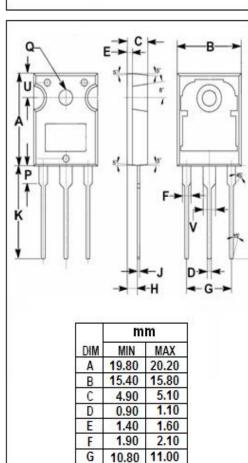
• ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	600	V
V _{GSS}	Gate-Source Voltage	±25	V
I _D	$\begin{array}{c} \text{Drain Current-Continuous@T}_{\text{C}}\text{=}25^{\circ}\!$	44 28	А
I _{DM}	Drain Current-Single Pulsed	176	A
P_D	Total Dissipation	330	W
T _{ch}	Max. Operating Junction Temperature	150	$^{\circ}$ C
T _{stg}	Storage Temperature	-55~150	$^{\circ}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.38	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	50	°C/W	





Н

K

Q

U

0.50

19.50

3.90

3.30

5.20

2.90

20.50

4.10

3.50

5.40



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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	600			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	V _{DS} = ±25V; I _D =0.25mA	2		4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =20A		55	70	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±25V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 600V; V _{GS} = 0V; T _J =25℃ T _J =125℃			1 100	μА
V _{SDF}	Diode forward voltage	I _{SD} =44A, V _{GS} = 0 V			1.6	V

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